Corrigendum

Corrigendum to “Enhanced Light Scattering by Preferred Orientation Control of Ga Doped ZnO Films Prepared through MOCVD”

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In the article titled “Enhanced Light Scattering by Preferred Orientation Control of Ga Doped ZnO Films Prepared through MOCVD” [1], Dr. Lu-Sheng Hong was missing from the authors’ list. The corrected authors’ list is shown above.

References

- [1] L. G. Bach, N. G. Nguyen, and V. T. Thanh Ho, “Enhanced light scattering by preferred orientation control of Ga doped ZnO films prepared through MOCVD,” *International Journal of Photoenergy*, vol. 2016, Article ID 1217576, 7 pages, 2016.